TOSHIBA 2SB1557

TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (DARLINGTON POWER TRANSISTOR)

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POWER AMPLIFIER APPLICATIONS

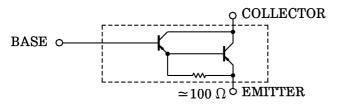
• High Breakdown Voltage : $V_{CEO} = -140 V$ (Min.)

• Complementary to 2SD2386

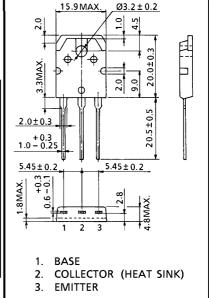
MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	-140	V
Collector-Emitter Voltage	v_{CEO}	-140	V
Emitter-Base Voltage	$v_{ m EBO}$	-5	V
Collector Current	$I_{\mathbf{C}}$	-7	A
Base Current	$I_{\mathbf{B}}$	-0.1	A
Collector Power Dissipation (Tc = 25°C)	$P_{\mathbf{C}}$	70	W
Junction Temperature	T_{j}	150	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

EQUIVALENT CIRCUIT



Unit in mm



JEDEC	_	
JEITA	_	
TOSHIBA	2-16C1A	

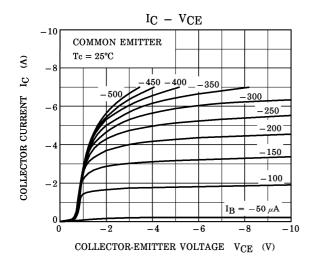
Weight: 4.7 g (Typ.)

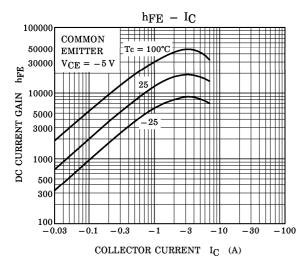
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

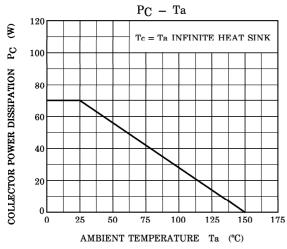
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -140 \text{ V}, I_{E} = 0$	_	_	-5.0	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-5.0	μ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{\rm C} = -50 {\rm mA}, \; I_{\rm B} = 0$	-140	_	_	V
IDC Current Gain	h _{FE (1)} (Note)	$V_{CE} = -5 \text{ V}, I_{C} = -6 \text{ A}$	5000	_	30000	
	h _{FE (2)}	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ A}$	2000	_	_	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{\rm C} = -6{\rm A},\ I_{\rm B} = -6{\rm mA}$	_	_	-2.5	V
Base-Emitter Voltage	$ m V_{BE}$	$V_{CE} = -5 \text{ V}, I_{C} = -6 \text{ A}$	_	_	-3.0	V
Transition Frequency	$ m f_{T}$	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ A}$	_	30	_	MHz
Collector Output Capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz	_	120	_	pF

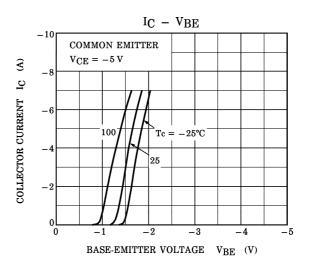
 $(Note): h_{FE\,(1)} \ Classification \\ A: 5000 \sim 12000, \ B: 9000 \sim 18000, \ C: 15000 \sim 30000$

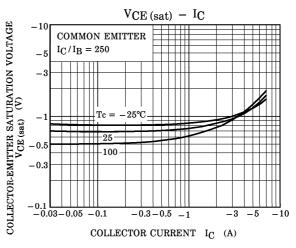
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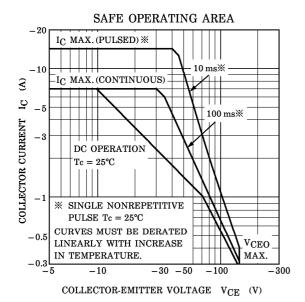








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